Ballistic Conductance through Porphyrin Nanoribbons

Jie-Ren Deng, M. Teresa González, He Zhu, Harry L. Anderson,* and Edmund Leary*

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ABSTRACT: The search for long molecular wires that can transport charge with maximum efficiency over many nanometers has driven molecular electronics since its inception. Single-molecule conductance normally decays with length and is typically far below the theoretical limit of $G_0$ (77.5 μS). Here, we measure the conductances of a family of edge-fused porphyrin ribbons (lengths 1–7 nm) that display remarkable behavior. The low-bias conductance is high across the whole series. Charging the molecules in situ results in a dramatic realignment of the frontier orbitals, increasing the conductance to $1 G_0$ (corresponding to a current of 20 μA). This behavior is most pronounced in the longer molecules due to their smaller HOMO–LUMO gaps. The conductance-voltage traces frequently exhibit peaks at zero bias, showing that a molecular energy level is in resonance with the Fermi level. This work lays the foundations for long, perfectly transmissive, molecular wires with technological potential.

INTRODUCTION

The inefficiency with which molecular junctions transport charge over distances longer than 1–2 nm is a key problem hindering the development of electronic circuits based on single molecules or monolayers. Studies on families of conjugated wires, predominantly connected between gold electrodes, generally show that conductance drops exponentially with distance, following the form

$$G(L) = A e^{-BL}.$$  

(1)

where $L$ is the molecular length, $A$ is a prefactor (which can be viewed as a contact resistance), and $B$ is the conductance attenuation factor describing how the conductance, $G$, decays with oligomer length.\(^1\)\(^-\)\(^6\) The main reason for the exponential decrease is an energy mismatch between the transporting molecular orbitals and the electrode Fermi level ($E_F$). In many experiments, $E_F$ is found to lie close to the center of the HOMO–LUMO gap, as demonstrated by the small voltage dependence of $G$ around 0 V and the typically low Seebeck coefficients.\(^7\)\(^-\)\(^17\) Although the HOMO–LUMO gap shrinks as the length of the π-conjugated oligomer increases, the greater tunneling distance tends to dominate, producing an exponential decay. For many π-conjugated chains, such as oligophenylene ethynylenes,\(^11\) oligofluorenes,\(^12\) oligoynes,\(^13,14\) and oligo[π]bis(triarylamines),\(^20\) and oligo[π]emeraldines,\(^21,22\) in these cases, however, the chemical stability usually drops rapidly with length, and it will be hard to use these materials in future componentry. Furthermore, a symmetry-breaking Peierls transition occurs beyond a critical length in highly symmetric molecules leading to conductance decay.\(^19\)\(^,\)\(^20\) Such limitations call for different strategies for producing long, stable, and maximally conducting junctions.

π-Conjugated porphyrin oligomers are excellent wires due to their efficient π-overlap, stability, rigid frameworks, and small reorganization energies.\(^3\)\(^-\)\(^6\)\(^,\)\(^19\)\(^,\)\(^20\) We recently showed that edge-fused porphyrins with up to three porphyrin subunits, connected to gold through thiolate groups, display ultralow bias\(^19\)\(^,\)\(^20\) sensitivity as a consequence of the rapidly decreasing HOMO–LUMO gap with length, which counters the greater tunneling distance. Remarkably, $B$ becomes negative above $\sim 0.7$ V, and hence $G$ increases with length. For the fused trimer, at $0.7–0.8$ V, $G \approx 10^{-2} G_0$, which is a factor 100 times greater than at low bias. As $V_{bias}$ was increased further, the conductance tended to level off, suggesting alignment between one of the frontier molecular orbitals and $E_F$ and, thus, a resonant-tunneling regime. In this regime, individual molecules have been shown to become charged, as demonstrated by hysteresis in successive bias sweeps.\(^24\) This underexplored phenomenon has only been reported for a few systems.\(^25\)\(^,\)\(^26\) It is significant that the charged molecule can maintain high conductance even as the bias is

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brought back to zero. This behavior can be rationalized in terms of a two-channel mechanism, as proposed by Migliore and Nizan, in which a fast, coherent channel determines the measured conductance, while a slow, hopping channel controls the charge state. The second channel effectively acts as an in situ gate, altering the alignment of the levels. We found that the high-conductance states of thiolate-anchored porphyrins can be stable over many seconds (limited in our case by instrument drift), which suggests this could be a viable route to form long, stable, and highly conductive molecular wires and perhaps even molecular-memory devices. Other kinds of bias-driven molecular-memory effects are known and are discussed elsewhere.

The aim of this project was to create long, highly conductive molecular junctions by combining two features: (i) a molecular wire with a low $\beta$-factor and (ii) an electronically transparent connection to the electrodes (i.e., high $A_{\text{el}}$ low contact resistance). The attachment of molecules to gold electrodes with covalent Au–C bonds has often been used to generate highly conductive junctions from short molecules. In this study, we tested various methods for attaching alkynes to gold electrodes and found that trimethylsilyl (TMS, i.e., SiMe$_3$) alkynes provide suitable connections. TMS-alkyne substituents are convenient proto-anchor groups because they are stable and easy to synthesize. We investigated charge transport through a series of edge-fused porphyrin nanoribbons consisting of up to eight nickel-porphyrin units terminating in TMS-alkynes, with lengths up to 7.1 nm, and found that these molecules give surprisingly transmissive junctions, reaching 1 $G_0$.

**RESULTS AND DISCUSSION**

**Model Studies and Selection of the TMS Anchor Group.** Many alkyne derivatives have been reported to act as anchor groups in AulmoleculeAu break-junctions. Sometimes the effectiveness of an anchor group depends on the type of molecular wire or experimental setup; so we tested porphyrin monomers ZnP1α–f (Figure 1, with X = H, SiMe$_3$, AuP(OMe)$_3$, AuPPh$_3$, Si(i-Pr)$_3$, and Me) to guide our choice of acetylene proto-anchor group for this study (see the Supporting Information for the synthesis of ZnP1α–f). Terminal alkynes (X = H) are known to adsorb covalently onto gold surfaces and to provide low-resistance junctions in gold break-junctions. On the other hand, some reports suggest that gold complexes, such as X = AuP(OMe)$_3$, give higher junction-formation probabilities. We tested the binding ability of ZnP1α–f using the scanning tunneling microscope break-junction (STM-BJ) technique to form single-molecule junctions. (A full description of data collection and post-processing is given in Supporting Information Section 2.2.) Our results (Figures 1 and S22–S24 for conductance histograms) show that ZnP1α–d gave junctions with conductances of $\log(G/G_0) = -1.0$ to $-3.0$, which is much higher than for analogous porphyrins with 4-AcS-C$_6$H$_4$C$_2$ anchors ($G \approx 10^{-4} G_0$, Figure S9). Several conductance groups could be distinguished, as discussed below. In contrast, ZnP1e and ZnP1f (X = Si(i-Pr)$_3$ and X = Me) gave no detectable junctions (Figure S24). We concluded that ZnP1β (X = SiMe$_3$) is the most convenient acetylene proto-anchor group because it gives similar junctions to ZnP1a, ZnP1c, and ZnP1d while being the most stable and synthetically accessible.

Previous work has shown that TMS-alkynes chemisorb onto gold Au(111) surfaces in a perpendicular orientation and that they can form effective AulmoleculeAu junctions. Some authors have reported that TMS-alkynes need activating with tetrabutyllumonium fluoride to form molecular junctions, although this does not always seem necessary. Here, we found that such activation was unnecessary. The similarity between the conductance histograms of ZnP1α–d and the high conductances of these junctions suggests that all four compounds give the same covalently bonded Au–C–C–C– connections, with spontaneous loss of the TMS group, probably through reaction with traces of moisture catalyzed by nascent gold adatoms in the break-junction. This hypothesis is supported by the observation that the triisopropylsilyl (TIPS) group in ZnP1e does not give molecular junctions (in keeping with the results of Ferradás et al.) because the Si–C bonds in TIPS-alkynes are generally much more robust than in TMS-alkynes. Further support for this is provided by the report that tert-butyl alkynes, Me$_2$C(=C–C=C–) do not form similar junctions as Me$_2$Si(=C–C=C–), despite the structural similarity. It has been suggested that TMS-alkynes bind to gold via five-coordinate trigonal-bipyramidal silicon, Au–SiMe$_3$–C–C–C–, but this is not supported by computational results. The observation that ZnP1f (X = Me) does not form junctions demonstrates that cleavage of the TMS group is required and that a side-on $\pi$-interaction alone is not sufficient to give a viable contact.

**Synthesis and Characterization of Porphyrin Nanoribbons.** The TMS-terminated porphyrin nanoribbons NiP1, NiP2, NiP4, NiP6, and NiP8 were synthesized as shown in Figure 2a (see the Supporting Information for details). These oligomers were metalated with nickel(II), rather than zinc, to
make them more resistant to accidental oxidation. *Meso*-3,5-bis(tri-*n*-hexylsilyl)phenyl substituents were used to avoid aggregation and achieve high solubility. The bulky side chains probably also prevent the flat faces of the porphyrins from adsorbing onto gold surfaces. Treatment of the singly-linked oligomers, *s*-ZnP, with *N*-bromosuccinimide resulted in efficient bromination of the terminal *meso*-positions to yield *s*-ZnP-Br. The coordinated metal was then changed to nickel(II) before oxidative fusion and Sonogashira coupling with TMS-acetylene. The presence of nickel(II) makes it necessary to use harsher conditions in the oxidative fusion step (*AuCl₃/AgOTf*) than would have been required for zinc(II) porphyrins. The well-resolved *¹H* NMR spectra (Figure 2b) and MALDI-ToF mass spectra (Supporting Information) confirm the purity, solubility, lack of aggregation, and absence of accidental oxidation in these compounds.

The UV−vis−NIR absorption spectra of NiP1, NiP2, NiP4, NiP6, and NiP8 illustrate the dramatic reduction in the HOMO−LUMO gap with length, as reported previously for similar edge-fused porphyrin nanoribbons. The transition energies of the longest wavelength absorption maxima (*E_g,opt* measured in CHCl₃ at 298 K) are plotted against 1/N in Figure 2c, showing a good fit to eq 2, which can be derived from a simple particle-in-a-box model, where N is the number of repeat units and *a*, *b*, and *c* are empirical parameters.

$$E_g = a + b\frac{1}{N} + c\frac{1}{N^2}$$  \hspace{1cm} (2)

Electrochemical measurements were also performed on NiP1, NiP2, and NiP4 (Supporting Information pages S33–S35). From these, it is possible to extrapolate an energy gap of the infinite polymer, which gave a value of 0.47 eV. Energy gaps from density functional theory (DFT) calculations (*E_g,DFT*) and transition energies from time-dependent DFT (*E_g,TD-DFT*), also shown in Figure 2c, match well with the experimental data (B3LYP/6-31G* level of theory; PCM solvent model, CHCl₃). The parameter *a* from the UV−vis−NIR data provides an estimate of the gap for the infinite polymer of 0.48 eV (*E_g,opt*; from the longest wavelength absorption maxima, which is very similar to the electrochemi-
Conductance Measurements on Porphyrin Nanoribbons. We used the STM-BJ technique to form single-molecule junctions of NiP1–NiP8 under ambient conditions in the absence of a solvent (see Supporting Information Section 7 for further details). The conductance of each compound was measured both at fixed low bias (0.2 V, Figure 3) and as a function of voltage between 0.0 V and 1.0 V. For each compound, we initially separated plateau-containing G-z traces from those with only background tunneling using an algorithm that searches for regions of constant conductance. Following this, we performed a k-means clustering analysis to remove very short plateaus (probably) arising from unsuccessful attach-
ments. The conductance of NiP1 lies in the range \( \log(G/G_0) = -1.5 \text{ to } -3.5 \), and the conductance histograms display three significant peaks (Figure 3b black curve) which we designate high, medium, and low (H, M, L, see Supporting Information Figure S5 for a labeled histogram). The k-means clustering analysis (Supporting Information Section 7.3) suggests that L corresponds to the fully-stretched junction, while M and H originate from compressed forms of the junction, which might be caused by differing degrees of \( \pi \)-overlap between the triple bond and the gold electrodes (Supporting Information Figure S8).

The 1D histogram of NiP2 (Figure 3b) is in the same conductance range as NiP1, but the G-z plateaus are correspondingly longer (see the 2D histograms in Figure 3d). There are two prominent peaks, with a third smaller peak on the low conductance side. For NiP4, the three-peak structure is still present, although there is a general shift to slightly lower conductance values and the histogram broadens. NiP6 and NiP8 continue this trend, displaying greater weight at yet lower conductance values, and the three-peak structure is no longer visible. The 2D histogram of NiP8 (with a molecular length over 7 nm) shows that junctions with conductance values above \( \log(G/G_0) = -3 \) typically extend to inter-electrode separations of 3.5–4.5 nm (after the gold snap-back is accounted for). The lower conducting junctions extend to between 4.5 and 5.5 nm, which approaches the maximum distance expected. To quantify the conductance for each compound, and determine a \( \beta \) value, we fitted each histogram with a single Gaussian curve that encompasses the entire conductance range, ignoring the discrete peaks. A linear fit to the natural logarithm of \( G \) (Supporting Information Figure S10) gave a \( \beta \) value of 0.33 (±0.08) nm\(^{-1}\), which is much lower than typical organic oligomers but similar to the value for short thiolate porphyrin nanoribbons (0.5 nm\(^{-1}\)).

The behavior of NiP1–NiP8 changes dramatically at higher bias voltages. We performed current vs voltage (I-V) ramps in the range ±1.0 V. For NiP1, all \( \log(G/G_0)-V \) traces (where \( G = I/V \)) show a slight increase in conductance of \( \Delta \log(G/G_0) = 0.2 \) between 0.0 V and ±1.0 V (Figure 4a, see Supporting Information Figure S11a for individual examples) and have a U-shape characteristic of off-resonant tunneling.\(^5\) The small increase shows that the lowest molecular level is energetically far from \( E_F \). The picture changes with NiP2, where only ~50% of the \( \log(G/G_0)-V \) traces are U-shaped. The low–high bias conductance increase is greater than that of NiP1 due to its smaller HOMO–LUMO gap (see Figure 2c for a plot of the HOMO–LUMO gap for each compound). The other 50% are different, having, for example, a \( V \) shape (see Supporting Information Figure S11c for examples) which indicates that molecules are charging due to the bias.\(^24\) This becomes possible due to the rapidly decreasing HOMO–LUMO gap with length (see Figure 2c and Supporting Information Figure S2 for the UV–vis–NIR and electrochemically-derived energy
gaps respectively). For the longer NiP4–NiP8 wires, the percentage of U-shaped traces further decreases to between 5 and 15% and, for NiP6 and NiP8, many level off at high bias (Supporting Information Figure S11b). We manually extracted the non-hysteretic U-shaped traces, which are shown as 2D histograms in Figure 4a (no separation was necessary for NiP1). The shrinking HOMO–LUMO gap can be inferred by the increasing degree of curvature and steepness, indicating that the closest molecular level approaches $E_F$ as the length of the oligomer increases. For a single molecular level ($\epsilon_0$) equally coupled to two electrodes, a maximum in $dI/dV$ would be expected when $\epsilon_0$ aligns with the chemical potential of either electrode. We found individual, low noise junctions with peaks in $dI/dV$ (Supporting Information Figure S16); however, maxima in the overall average $dI/dV$ trace were not very clear (Supporting Information Figure S17), which could suggest a degree of averaging-out of detail. Some deviation from ideal single-level behavior may occur if $E_F$ sits close to the center of the HOMO–LUMO gap, causing both levels to contribute to transport. Closely spaced levels beyond the frontier orbital which come into play at high bias (as suggested from our electrochemical study) may also lead to deviations from the ideal single-level picture in this regime. Interestingly, plots of $d(\log(G/G_0))/dV$ (Figure 4b) show clear peaks (for NiP4–NiP8) which drop toward zero at higher bias (NiP6–NiP8). Plotting the corresponding energy shift of the chemical potentials ($E = eV/2$) at the peak (black bars, Figure 4c) and zero–crossing points (red bars, obtained by extrapolating to zero) more easily allows us to approximate the position of $\epsilon_0$. The blue circles show the gaps obtained from our UV–vis–NIR measurements. For further comparison, we fitted the overall average $I-V$ curve, as well as a selection of individual $I-V$ curves for NiP8, using the temperature-dependent single-level model (SLM, Supporting Information Figures S14 and S15). Extracted parameters for the average trace were $\Gamma_{\text{left/right}} = 1.6$ meV and $E_F-\epsilon_0 = 0.32$ eV, which fits with the estimated position above. Again, better fits were obtained for individual traces, which gave values of $E_F-\epsilon_0$ between 0.29–0.35 eV. These results show overall that for each molecule, $E_F$ likely sits close to the center of the HOMO–LUMO gap.

Figure 5a shows a reversible G-V trace (plotted as $\log(G/G_0)$–$V$) for NiP6 (black trace recorded first, followed by the red trace), in which the junction is brought smoothly into and out of resonance. The G-V curve starts leveling at ca(XXX), which is within the bias window. Further increase of $V_{\text{bias}}$ may thus bring more levels into resonance. Figure 5b,c shows the situation when a junction becomes hysteretic (in this case for NiP8). This is when voltage-induced charging takes place. The lack of hysteresis for NiP1 also proves that the small HOMO–LUMO gaps in the longer oligomers facilitate charging during bias sweeps. The charged-state lifetime can vary, as seen by comparing panels b and c. Intriguingly, Figure 5d shows a new phenomenon that we have not previously observed. Initially, $E_0$
sits within the bias window (black trace, starting at $-0.7$ V) where $\log(G/G_0) = -0.5$ ($0.3 \ G_0$, i.e., a highly conducting junction). As $V_{\text{bias}}$ is reduced, $G$ drops rapidly, reaching a minimum between $\pm 0.25$ V, 10 times lower than on resonance, and then rises rapidly as $V_{\text{bias}}$ is again brought back into resonance. Around $+0.7$ V, however, the junction switches and the red return trace is completely different, showing a peak centered at 0 V. The conductance is now extremely high ($G_0 = 0.6 \ G_0$, which is 30 times greater than in the black trace) and close to the maximum possible through a single molecular level.

We now focus on NiP8 to describe this extraordinary high-bias behavior. We found 125 junctions (18% of the total) which, when the bias was swept between $\pm 1.0$ V, displayed low-bias conductances above 0.1 $G_0$, a range which is 30 times greater than in the black trace) and close to the maximum possible through a single molecular level.

Figure 5. (a–d) Examples of log(conductance) vs voltage (log(G-V)) sweeps recorded on molecular junctions of NiP6 and NiP8. In each case, the black trace is recorded first (starting at $-1.0$ V) followed by the red trace (which starts at $+1.0$ V). Colored arrows indicate the direction of the bias sweep. (a) Reversible traces for NiP6. (b) Short-lived charged state for NiP8 (hysteresis can be seen in the yellow-shaded region). (c) Long-lived charged state of NiP8 in which the junction starts off-resonant (black trace), charges while under high bias, and then remains in the high-conductance state (red trace) but with significant fluctuations. (d) Junction that switches from off-resonant to on-resonant, showing a peak at zero bias. (e) Examples of ultraconducting charged molecular junctions of NiP8. The inset shows a magnified view of the left-hand trace showing periodic jumps in conductance that occur approximately every 2–3 Å. (f) 1D conductance histogram built from 60 of the most-conductive junctions. (g) 2D conductance-distance histograms from the same data. (h) Further examples of log(G/G_0)-V traces showing a peak at zero bias from junctions with conductances close to 1 $G_0$. Each example is taken from a separate molecular junction.
We also observed much larger G jumps than previously seen at fixed low bias, between approximately $10^{-4}$ $G_0$ and $10^{-1}$ $G_0$, which we attribute to spontaneous charging events (Supporting Information Figure S20).

G-V curves recorded during evolution of ultra-G junctions varied, but remarkably S3 junctions displayed well-defined peaks in G at zero bias. In total, we recorded 118 individual G-V traces of this type (6% of all the G-V traces recorded on ultra-G junctions, Figure 5h, see also Supporting Information Figure S19). We are unaware of this phenomenon in other room-temperature single-molecule junctions. Zero-bias peaks are expected for Kondo resonances,58 but as we are well above the Kondo temperature previously measured for a porphyrin nanoribbon,59 we rule this out. Instead, we attribute them to a near-perfectly aligned molecular orbital with $E_F$. The energy level schemes shown in Figure 6 provide an explanation. The key ingredients are a well-coupled level ($\epsilon_0$) responsible for the current and a weakly coupled level ($\epsilon_{\pm 1}$) responsible for charging. The HOMO of oligo(porphyrins) generally shows large weight at the meso positions which results in strong molecule-electrode coupling, while the HOMO−1 typically displays a node at this position and is, therefore, weakly coupled.54 After charging, repositioning of the levels takes place (Figure 6c,d), where the final alignment of $\epsilon_0$ (strongly coupled level) determines the precise shape of the G-V trace.

When $\epsilon_0$ aligns right at $E_F$, a peak in G appears. We compared a sequence of log($G/G_0$)-V traces in which transport switched from off-resonant to on-resonant with the SLM (Supporting Information Figure S19a,b). The SLM captures the dramatic change in the shape of the traces when $\epsilon_0$ shifts. A zero-bias peak is only produced when $\epsilon_0$ is closer than ~0.05 eV. The zero-bias peak in Supporting Information Figure S18, for example, could be fitted with the following parameters: $\Gamma_{\text{left/right}} = 2$ meV and $E - \epsilon_0 = 0.01$ eV, showing that the coupling is in the same range after charging, but $\epsilon_0$ now lies at $E_F$. This shows how molecules can behave like metal chains and conduct perfectly at low bias. This opens up the exciting possibility of moving beyond 10 nm in single-molecule conductance experiments.

## CONCLUSIONS

We studied a family of edge-fused porphyrin nanoribbons up to 7.1 nm in length (8 porphyrin units) by using the STM-BJ technique. Low-resistance gold-acetylide contacts give large low-bias conductances up to $10^{-2}$ $G_0$ but also show that electron transport is still suppressed relative to an ideal system. Remarkably, bias-induced charging causes a dramatic realignment of the frontier orbitals, producing stable junctions with conductance up to 1 $G_0$. In this regime, we observed a new feature in conductance-voltage traces with peaks at 0 V, showing that a level lies right at the Fermi level. This study proves it is possible for molecular wires in the 5–10 nm range, with well-defined atomic binding groups, to have perfect electronic transmission. The challenge is now to explore the limits of this ballistic transport regime in molecules and also learn how to manipulate it.

## ASSOCIATED CONTENT

* Supporting Information

The Supporting Information is available free of charge at https://pubs.acs.org/doi/10.1021/jacs.3c07734.

Synthetic procedures, characterization data, UV−vis−NIR spectra, electrochemical measurements, DFT and TDFT simulations, STM-BJ measurements (PDF)

## AUTHOR INFORMATION

### Corresponding Authors

Harry L. Anderson − Department of Chemistry, Chemistry Research Laboratory, Oxford University, Oxford OX1 3TA, U.K.; orcid.org/0000-0002-1801-8132; Email: harry.anderson@chem.ox.ac

Edmund Leary − Fundación IMDEA Nanociencia, 28049 Madrid, Spain; orcid.org/0000-0001-7541-5997; Email: edmund.leary@imdea.org

### Authors

Jie-Ren Deng − Department of Chemistry, Chemistry Research Laboratory, Oxford University, Oxford OX1 3TA, U.K.

M. Teresa González − Fundación IMDEA Nanociencia, 28049 Madrid, Spain; orcid.org/0000-0002-7253-797X

He Zhu − Department of Chemistry, Chemistry Research Laboratory, Oxford University, Oxford OX1 3TA, U.K.

Complete contact information is available at: https://pubs.acs.org/10.1021/jacs.3c07734

### Notes

The authors declare no competing financial interest.
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(56) We attempted to separate the different shaped traces using a k-means clustering algorithm, however, this proved unsuccessful as we found that the algorithm did not effectively distinguish ‘V’ shaped from ‘U’ shaped traces.

